

OVERVIEW

The SM5009 series are crystal oscillator module ICs that incorporate low crystal current type oscillating circuit to limit oscillator-stage current, so that they can reduce crystal current lower than the existing products. Since the oscillating circuit has oscillator capacitors with excellent frequency response and feedback resistor built-in, just connecting crystal realizes stable fundamental oscillation responding up to 40MHz. The SM5009 series are ideal for SMD type crystal oscillator using a strip-shaped crystal blank.

FEATURES

- Low crystal current oscillator
- Up to 40MHz operating frequency range (fundamental oscillation)
- Operating supply voltage range
 - 3V operation: 2.7 to 3.6V
 - 5V operation: 4.5 to 5.5V
- -40 to 85°C operating temperature range
- Oscillation capacitors C_G , C_D built-in
- Inverter amplifier feedback resistor built-in
- Standby function
 - Oscillator stops (AL series), high impedance in standby mode
- Low standby current
- Power-save pull-up resistor built-in (AL series)
- Frequency divider built-in (f_O , $f_O/2$, $f_O/4$, $f_O/8$, $f_O/16$, $f_O/32$ determined by internal connection)
- Output drive capability
 - AL×, AN×, AK×, CN×: 16mA ($V_{DD} = 4.5V$)
 - AH×: 4mA ($V_{DD} = 4.5V$)
- Output load: $C_L = 50pF$ max.
- Output duty level
 - CMOS level ($1/2 V_{DD}$): AL×, AN×, AH×, CN×
 - TTL level (1.4V): AK×
- Molybdenum-gate CMOS process
- 8-pin SOP (SM5009×××S)
- Chip form (CF5009×××)

SERIES CONFIGURATION

| Version ¹ | 3V operation | | 5V operation | | Output duty level | Output frequency | INH Input level | Standby mode | |
|----------------------|--|-------------------------------------|--|-------------------------------------|-------------------|------------------|-----------------|--------------------------|--------------|
| | Recommended operating frequency range ² [MHz] | Output load ³ (max) [pF] | Recommended operating frequency range ² [MHz] | Output load ³ (max) [pF] | | | | Oscillator stop function | Output state |
| CF5009AL1 | Up to 40 | 50 | Up to 40 | 50 | CMOS | f_O | CMOS | Yes | Hi-Z |
| CF5009AL2 | | | | | | $f_O/2$ | | | |
| CF5009AL3 | | | | | | $f_O/4$ | | | |
| CF5009AL4 | | | | | | $f_O/8$ | | | |
| CF5009AL5 | | | | | | $f_O/16$ | | | |
| CF5009AL6 | | | | | | $f_O/32$ | | | |
| CF5009AN1 | Up to 40 | 30 | Up to 40 | 50 | CMOS | TTL | No | Hi-Z | |
| CF5009AN2 | | | | | f_O | | | | |
| CF5009AN3 | | | | | $f_O/2$ | | | | |
| CF5009AN4 | | | | | $f_O/4$ | | | | |
| CF5009AN5 | | | | | $f_O/8$ | | | | |
| CF5009AN6 | | | | | $f_O/16$ | | | | |
| CF5009CN1 | Up to 30 | 15 | Up to 30 | 50 | CMOS | TTL | No | Hi-Z | |
| CF5009CN2 | | | | | f_O | | | | |
| CF5009AK1 | - | - | Up to 40 | 15 | TTL | TTL | No | Hi-Z | |
| CF5009AK2 | | | | | $f_O/2$ | | | | |
| CF5009AH1 | Up to 16 | 15 | Up to 30 | 15 | CMOS | f_O | TTL | No | Hi-Z |
| CF5009AH2 | | | | | | $f_O/2$ | | | |
| CF5009AH3 | | | | | | $f_O/4$ | | | |
| CF5009AH4 | | | | | | $f_O/8$ | | | |

1. Package devices (8-pin SOP) have designation SM5009×××S.

2. The recommended operating frequency is a yardstick value derived from the crystal used for NPC characteristics authentication. However, the oscillator frequency band is not guaranteed. Specifically, the characteristics can vary greatly due to crystal characteristics and mounting conditions, so the oscillation characteristics of components must be carefully evaluated.

3. Output load value is the maximum load capacitance that allows drive.

APPLICATIONS

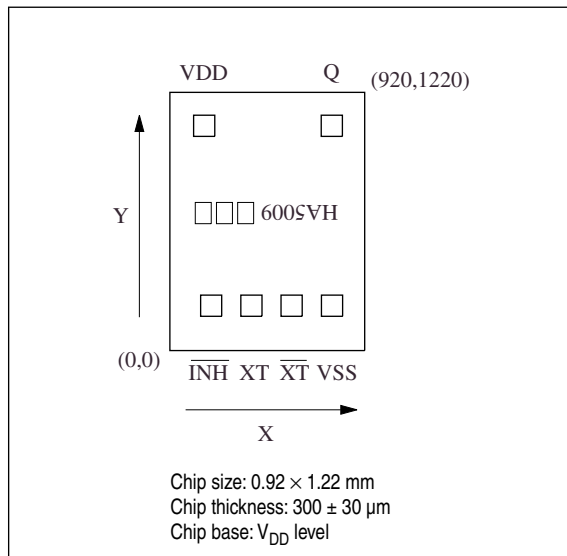
- SMD type crystal oscillator module

ORDERING INFORMATION

| Device | Package |
|-------------|-----------|
| SM5009×××S | 8-pin SOP |
| CF5009×××-1 | Chip form |

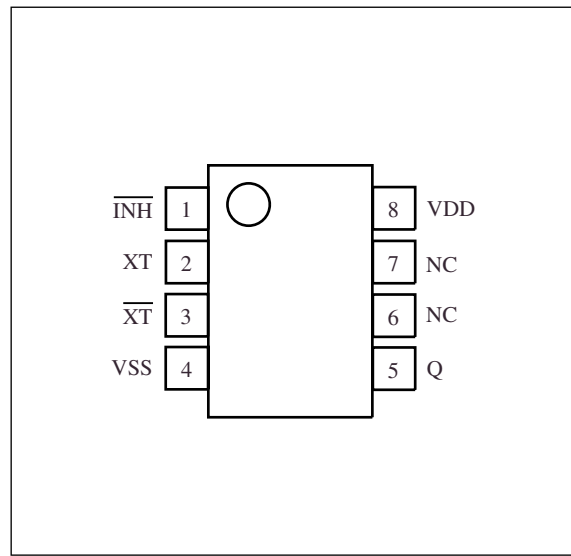
PAD LAYOUT

(Unit: μm)



PINOUT

(Top view)



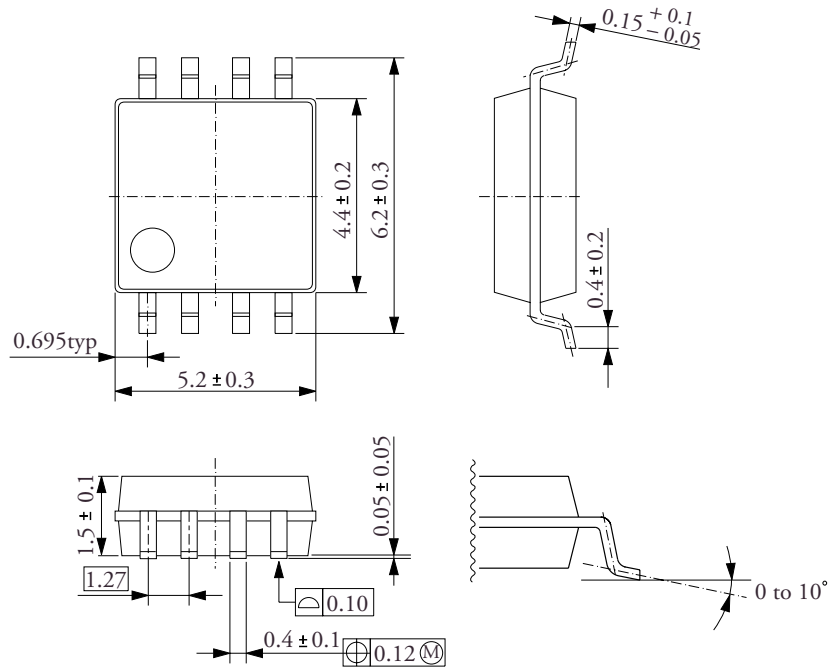
PIN DESCRIPTION and PAD DIMENSIONS

| Number | Name | I/O | Description | Pad dimensions [μm] | |
|--------|------|-----|--|----------------------------------|------|
| | | | | X | Y |
| 1 | INH | I | Output state control input. Standby mode when LOW, pull-up resistor built-in. In the case of the CF5009ALx, the oscillator stops and power-save pull-up resistor built in to reduce current consumption at standby mode. | 195 | 212 |
| 2 | XT | I | Amplifier input. | 385 | 212 |
| 3 | XT | O | Amplifier output. | | |
| | | | Crystal oscillator connection pins. Crystal oscillator connected between XT and XT | 575 | 212 |
| 4 | VSS | - | Ground | 766 | 212 |
| 5 | Q | O | Output. Output frequency (f_0 , $f_0/2$, $f_0/4$, $f_0/8$, $f_0/16$, $f_0/32$) determined by internal connection | 765 | 1062 |
| 6 | NC | - | No connection | - | - |
| 7 | NC | - | No connection | - | - |
| 8 | VDD | - | Supply voltage | 162 | 1062 |

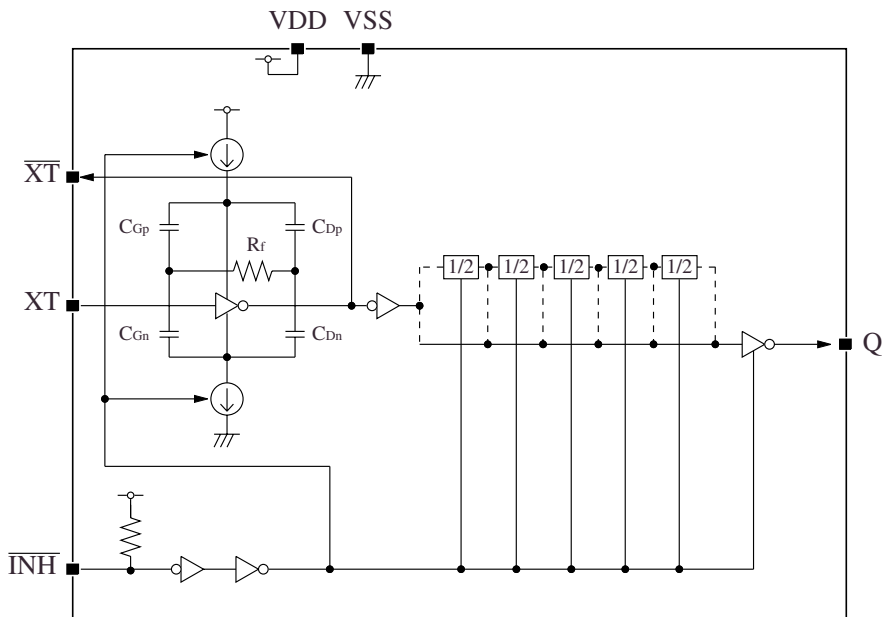
PACKAGE DIMENSIONS

(Unit: mm)

- 8-pin SOP



BLOCK DIAGRAM



Notes. The SM5009 series reduce crystal current by limiting driving current of oscillating-stage inverter and inhibiting oscillating amplitude. Depending on the characteristics of using crystal or the mounting condition, they may not oscillate normally. Please evaluate the oscillation start-up characteristics adequately with your actual device.

FUNCTIONAL DESCRIPTION

Standby Function

5009 AL× series

When $\overline{\text{INH}}$ goes LOW, the oscillator stops and the oscillator output on Q becomes high impedance.

5009AH×, AK×, AN×, CN× series

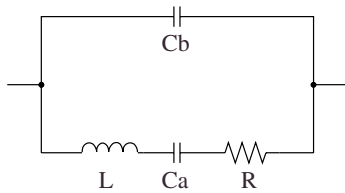
When $\overline{\text{INH}}$ goes LOW, the output on Q becomes high impedance, but internally the oscillator does not stop.

| Version | $\overline{\text{INH}}$ | Q | Oscillator |
|---------------------------|-------------------------|---|------------------|
| AL× series | HIGH (or open) | Any f_0 , $f_0/2$, $f_0/4$, $f_0/8$, $f_0/16$ or $f_0/32$ output frequency | Normal operation |
| | LOW | High impedance | Stopped |
| AH×, AK×, AN×, CN× series | HIGH (or open) | Any f_0 , $f_0/2$, $f_0/4$, $f_0/8$, $f_0/16$ or $f_0/32$ output frequency | Normal operation |
| | LOW | High impedance | Normal operation |

Power-save Pull-up Resistance (AL× series only)

The $\overline{\text{INH}}$ pull-up resistance changes in response to the input level (HIGH or LOW). When $\overline{\text{INH}}$ goes LOW (standby state), the pull-up resistance becomes large to reduce the current consumption during standby.

Current consumption and Output waveform with NPC's standard crystal



| f [MHz] | R [Ω] | L [mH] | Ca [fF] | Cb [pF] |
|---------|----------------|--------|---------|---------|
| 30 | 17.2 | 4.36 | 6.46 | 2.26 |
| 40 | 16.8 | 2.90 | 5.47 | 2.08 |

SPECIFICATIONS

Absolute Maximum Ratings

$V_{SS} = 0V$ unless otherwise noted.

| Parameter | Symbol | Condition | Rating | Unit |
|-----------------------------|-----------|-----------|------------------------|------|
| Supply voltage range | V_{DD} | | -0.5 to +7.0 | V |
| Input voltage range | V_{IN} | | -0.5 to $V_{DD} + 0.5$ | V |
| Output voltage range | V_{OUT} | | -0.5 to $V_{DD} + 0.5$ | V |
| Operating temperature range | T_{opr} | | -40 to +85 | °C |
| Storage temperature range | T_{stg} | Chip form | -65 to +150 | °C |
| | | 8-pin SOP | -55 to +125 | |
| Output current | I_{OUT} | | 25 | mA |
| Power dissipation | P_D | 8-pin SOP | 500 | mW |

Recommended Operating Conditions

$V_{SS} = 0V$ unless otherwise noted.

| Parameter | Symbol | Version | Condition | Rating | | | Unit | |
|---|-----------------------|-------------|---|---|------|----------|------|----|
| | | | | min | typ | max | | |
| Supply voltage | V_{DD} | AH× | $f \leq 30\text{MHz}$ | 4.5 | - | 5.5 | V | |
| | | | $f \leq 16\text{MHz}$ | 2.7 | - | 3.3 | | |
| | | AK× | $f \leq 40\text{MHz}$ | | 4.5 | - | 5.5 | V |
| | | | | | 2.7 | - | 5.5 | V |
| | | CN× | $f \leq 30\text{MHz}$ | | 2.7 | - | 5.5 | V |
| | | | | | 2.7 | - | 5.5 | V |
| | | AL× | Chip form | $f \leq 40\text{MHz}$ | 2.7 | - | 5.5 | V |
| | | | | $f \leq 30\text{MHz}$ | 2.3 | - | 2.7 | |
| | | | | $f \leq 20\text{MHz}$ | 2.25 | - | 2.75 | |
| | | | | $f \leq 14.4\text{MHz}$ | 2.4 | - | 2.7 | |
| 8-pin SOP | $f \leq 40\text{MHz}$ | | 2.7 | - | 5.5 | | | |
| | | | 2.4 | - | 2.7 | | | |
| Input voltage | V_{IN} | All version | | V_{SS} | - | V_{DD} | V | |
| Operating temperature | T_{OPR} | AH× | $f \leq 30\text{MHz}, 4.5V \leq V_{DD} \leq 5.5V$ | -40 | - | +85 | °C | |
| | | | $f \leq 16\text{MHz}, 2.7V \leq V_{DD} \leq 3.6V$ | -20 | - | +80 | | |
| | | AK× | $f \leq 30\text{MHz}$ $30\text{MHz} < f \leq 40\text{MHz}$ | | -40 | - | +85 | °C |
| | | | | | -20 | - | +80 | |
| | | AN× | Chip form | $f \leq 40\text{MHz}, 2.7V \leq V_{DD} < 4.5V$ | -20 | - | +80 | °C |
| | | | | $f \leq 40\text{MHz}, 4.5V \leq V_{DD} \leq 5.5V$ | -40 | - | +85 | |
| | | | 8-pin SOP | $f \leq 40\text{MHz}, 2.7V \leq V_{DD} < 4.5V$ | -20 | - | +80 | |
| | | | | $f \leq 40\text{MHz}, 4.5V \leq V_{DD} \leq 5.5V$ | -20 | - | +80 | |
| | | 8-pin SOP | $f \leq 30\text{MHz}, 4.5V \leq V_{DD} \leq 5.5V$ | | -40 | - | +85 | |
| | | | | | -40 | - | +85 | |
| | | CN× | $f \leq 30\text{MHz}, 2.7V \leq V_{DD} < 4.5V$ $f \leq 30\text{MHz}, 4.5V \leq V_{DD} \leq 5.5V$ | | -10 | - | +70 | °C |
| | | | | | -40 | - | +85 | |
| | | AL× | Chip form | $f \leq 40\text{MHz}, 2.7V \leq V_{DD} \leq 5.5V$ | -40 | - | +85 | °C |
| | | | | $f \leq 30\text{MHz}, 2.3V \leq V_{DD} \leq 2.7V$ | -20 | - | +80 | |
| | | | | $f \leq 20\text{MHz}, 2.25V \leq V_{DD} \leq 2.75V$ | -20 | - | +80 | |
| | | | 8-pin SOP | $f \leq 40\text{MHz}, 2.7V \leq V_{DD} \leq 5.5V$ | -20 | - | +80 | |
| $f \leq 30\text{MHz}, 2.7V \leq V_{DD} \leq 5.5V$ | -40 | | | - | +85 | | | |
| $f \leq 14.4\text{MHz}, 2.4V \leq V_{DD} \leq 2.7V$ | -20 | | | - | +80 | | | |

Electrical Characteristics

5009AL× series

3V operation: $V_{DD} = 2.7$ to $3.3V$, $V_{SS} = 0V$, $T_a = -40$ to $85^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | Rating | | | Unit | |
|-------------------------------------|-----------|--|-------------|------|-------------|-----------|----|
| | | | min | typ | max | | |
| HIGH-level output voltage | V_{OH} | Q: Measurement cct 1, $I_{OH} = 8mA$ | 2.2 | – | – | V | |
| LOW-level output voltage | V_{OL} | Q: Measurement cct 1, $I_{OL} = 8mA$ | – | – | 0.4 | V | |
| HIGH-level input voltage | V_{IH} | \overline{INH} | $0.7V_{DD}$ | – | – | V | |
| LOW-level input voltage | V_{IL} | \overline{INH} | – | – | $0.3V_{DD}$ | V | |
| Output leakage current | I_Z | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OH} = V_{DD}$ | – | – | 10 | μA | |
| | | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OL} = V_{SS}$ | – | – | 10 | | |
| Current consumption | I_{DD} | $\overline{INH} = open$, Measurement cct 3, load cct 2, $C_L = 15pF$, 40MHz crystal oscillator | CF5009AL1 | – | 8 | 17 | mA |
| | | | CF5009AL2 | – | 5 | 11 | |
| | | | CF5009AL3 | – | 4 | 9 | |
| | | | CF5009AL4 | – | 3 | 7 | |
| | | | CF5009AL5 | – | 3 | 6 | |
| | | | CF5009AL6 | – | 2 | 5 | |
| | | $\overline{INH} = open$, Measurement cct 3, load cct 2, $C_L = 15pF$, 40MHz crystal oscillator, $T_a = -20$ to $+80^\circ C$ | SM5009AL1S | – | 8 | 17 | |
| | | | SM5009AL2S | – | 5 | 11 | |
| | | | SM5009AL3S | – | 4 | 9 | |
| | | | SM5009AL4S | – | 3 | 7 | |
| | | | SM5009AL5S | – | 3 | 6 | |
| SM5009AL6S | – | 2 | 5 | | | | |
| Standby current | I_{ST} | $\overline{INH} = V_{SS}$, Measurement cct 3 | – | 2 | 5 | μA | |
| \overline{INH} pull-up resistance | R_{UP1} | Measurement cct 4, $V_{DD} = 3V$, $\overline{INH} = V_{SS}$ | 0.6 | – | 12 | $M\Omega$ | |
| | R_{UP2} | Measurement cct 4, $V_{DD} = 3V$, $\overline{INH} = 2.1V$ | 40 | – | 200 | $k\Omega$ | |
| Negative resistance | $-R_L$ | $V_{DD} = 3V$, $T_a = 25^\circ C$, 40MHz | – | –200 | – | Ω | |
| Feedback resistance | R_f | Measurement cct 5 | 0.4 | – | 1.1 | $M\Omega$ | |
| Built-in capacitance | C_G | Design value. A monitor pattern on a wafer is tested. | 5.58 | 6 | 6.42 | pF | |
| | C_D | | 9.3 | 10 | 10.7 | pF | |

SM5009 series

5V operation: $V_{DD} = 4.5$ to $5.5V$, $V_{SS} = 0V$, $T_a = -40$ to $85^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | Rating | | | Unit | |
|-------------------------------------|-----------|--|-------------|------|-------------|-----------|----|
| | | | min | typ | max | | |
| HIGH-level output voltage | V_{OH} | Q: Measurement cct 1, $I_{OH} = 16mA$ | 4.0 | – | – | V | |
| LOW-level output voltage | V_{OL} | Q: Measurement cct 1, $I_{OL} = 16mA$ | – | – | 0.4 | V | |
| HIGH-level input voltage | V_{IH} | \overline{INH} | $0.7V_{DD}$ | – | – | V | |
| LOW-level input voltage | V_{IL} | \overline{INH} | – | – | $0.3V_{DD}$ | V | |
| Output leakage current | I_Z | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OH} = V_{DD}$ | – | – | 10 | μA | |
| | | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OL} = V_{SS}$ | – | – | 10 | | |
| Current consumption | I_{DD} | $\overline{INH} = open$, Measurement cct 3, load cct 2, $C_L = 15pF$, 40MHz crystal oscillator | CF5009AL1 | – | 12 | 26 | mA |
| | | | CF5009AL2 | – | 8 | 17 | |
| | | | CF5009AL3 | – | 6 | 13 | |
| | | | CF5009AL4 | – | 5 | 11 | |
| | | | CF5009AL5 | – | 5 | 10 | |
| | | | CF5009AL6 | – | 4 | 9 | |
| | | $\overline{INH} = open$, Measurement cct 3, load cct 2, $C_L = 15pF$, 40MHz crystal oscillator, $T_a = -20$ to $+80^\circ C$ | SM5009AL1S | – | 12 | 26 | |
| | | | SM5009AL2S | – | 8 | 17 | |
| | | | SM5009AL3S | – | 6 | 13 | |
| | | | SM5009AL4S | – | 5 | 11 | |
| | | | SM5009AL5S | – | 5 | 10 | |
| | | | SM5009AL6S | – | 4 | 9 | |
| Standby current | I_{ST} | $\overline{INH} = V_{SS}$, Measurement cct 3 | – | 6 | 15 | μA | |
| \overline{INH} pull-up resistance | R_{UP1} | Measurement cct 4, $V_{DD} = 5V$, $\overline{INH} = V_{SS}$ | 0.3 | – | 6 | $M\Omega$ | |
| | R_{UP2} | Measurement cct 4, $V_{DD} = 5V$, $\overline{INH} = 3.5V$ | 40 | – | 200 | $k\Omega$ | |
| Negative resistance | $-R_L$ | $V_{DD} = 5V$, $T_a = 25^\circ C$, 40MHz | – | –400 | – | Ω | |
| Feedback resistance | R_f | Measurement cct 5 | 0.4 | – | 1.1 | $M\Omega$ | |
| Built-in capacitance | C_G | Design value. A monitor pattern on a wafer is tested. | 5.58 | 6 | 6.42 | pF | |
| | C_D | | 9.3 | 10 | 10.7 | pF | |

SM5009 series

5009AN×/CN× series

3V operation: $V_{DD} = 2.7$ to $3.3V$, $V_{SS} = 0V$, $T_a = -20$ to $80^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | Rating | | | Unit | |
|-------------------------------------|----------|---|--|------|------|-----------|----|
| | | | min | typ | max | | |
| HIGH-level output voltage | V_{OH} | Q: Measurement cct 1, $I_{OH} = 8mA$ | SM5009AN1S, CF5009AN1 SM5009AN2S, CF5009AN2 | 2.2 | – | – | V |
| | | | SM5009AN3S, CF5009AN3 SM5009AN4S, CF5009AN4 SM5009AN5S, CF5009AN5 SM5009AN6S, CF5009AN6 SM5009CN1S, CF5009CN1 SM5009CN2S, CF5009CN2 | 2.1 | – | – | |
| LOW-level output voltage | V_{OL} | Q: Measurement cct 1, $I_{OL} = 8mA$ | – | – | 0.4 | V | |
| HIGH-level input voltage | V_{IH} | \overline{INH} | 2.0 | – | – | V | |
| LOW-level input voltage | V_{IL} | \overline{INH} | – | – | 0.3 | V | |
| Output leakage current | I_z | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OH} = V_{DD}$ | – | – | 10 | μA | |
| | | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OL} = V_{SS}$ | – | – | 10 | | |
| Current consumption | I_{DD} | $\overline{INH} = open$, Measurement cct 3, load cct 2, $C_L = 15pF$, 40MHz crystal oscillator | SM5009AN1S, CF5009AN1 | – | 8 | 17 | mA |
| | | | SM5009AN2S, CF5009AN2 | – | 5 | 11 | |
| | | | SM5009AN3S, CF5009AN3 | – | 4 | 9 | |
| | | | SM5009AN4S, CF5009AN4 | – | 3 | 7 | |
| | | | SM5009AN5S, CF5009AN5 | – | 3 | 6 | |
| | | | SM5009AN6S, CF5009AN6 | – | 2 | 5 | |
| | | $\overline{INH} = open$, Measurement cct 3, load cct 2, $C_L = 15pF$, 30MHz crystal oscillator, $T_a = -10$ to $+70^\circ C$ | SM5009CN1S, CF5009CN1 | – | 7 | 15 | |
| | | | SM5009CN2S, CF5009CN2 | – | 4 | 9 | |
| \overline{INH} pull-up resistance | R_{UP} | Measurement cct 4, $V_{DD} = 3V$, $\overline{INH} = V_{SS}$ | 40 | – | 200 | $k\Omega$ | |
| Negative resistance | $-R_L$ | $V_{DD} = 3V$, $T_a = 25^\circ C$, 40MHz | – | –100 | – | Ω | |
| Feedback resistance | R_f | Measurement cct 5 | 0.4 | – | 1.1 | $M\Omega$ | |
| Built-in capacitance | C_G | Design value. A monitor pattern on a wafer is tested. | 5.58 | 6 | 6.42 | pF | |
| | C_D | | 9.3 | 10 | 10.7 | pF | |

SM5009 series

5V operation: $V_{DD} = 4.5$ to $5.5V$, $V_{SS} = 0V$, $T_a = -40$ to $85^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | Rating | | | Unit | |
|--|-----------------------|---|--|------|------|-----------|----|
| | | | min | typ | max | | |
| HIGH-level output voltage | V_{OH} | Q: Measurement cct 1, $I_{OH} = 16mA$ | SM5009AN1S, CF5009AN1 SM5009AN2S, CF5009AN2 | 4.0 | – | – | V |
| | | | SM5009AN3S, CF5009AN3 SM5009AN4S, CF5009AN4 SM5009AN5S, CF5009AN5 SM5009AN6S, CF5009AN6 SM5009CN1S, CF5009CN1 SM5009CN2S, CF5009CN2 | 3.9 | – | – | |
| LOW-level output voltage | V_{OL} | Q: Measurement cct 1, $I_{OL} = 16mA$ | – | – | 0.4 | V | |
| HIGH-level input voltage | V_{IH} | \overline{INH} | 2.0 | – | – | V | |
| LOW-level input voltage | V_{IL} | \overline{INH} | – | – | 0.8 | V | |
| Output leakage current | I_z | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OH} = V_{DD}$ | – | – | 10 | μA | |
| | | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OL} = V_{SS}$ | – | – | 10 | | |
| Current consumption | I_{DD} | $\overline{INH} = open$, Measurement cct 3, load cct 2, $C_L = 15pF$, 40MHz crystal oscillator | CF5009AN1 | – | 12 | 26 | mA |
| | | | CF5009AN2 | – | 8 | 17 | |
| | | | CF5009AN3 | – | 6 | 13 | |
| | | | CF5009AN4 | – | 5 | 11 | |
| | | | CF5009AN5 | – | 5 | 10 | |
| | | | CF5009AN6 | – | 4 | 9 | |
| | | $\overline{INH} = open$, Measurement cct 3, load cct 2, $C_L = 15pF$, 40MHz crystal oscillator, $T_a = -20$ to $+80^\circ C$ | SM5009AN1S | – | 12 | 26 | |
| | | | SM5009AN2S | – | 8 | 17 | |
| | | | SM5009AN3S | – | 6 | 13 | |
| | | | SM5009AN4S | – | 5 | 11 | |
| | | | SM5009AN5S | – | 5 | 10 | |
| | | | SM5009AN6S | – | 4 | 9 | |
| $\overline{INH} = open$, Measurement cct 3, load cct 2, $C_L = 15pF$, 30MHz crystal oscillator | SM5009CN1S, CF5009CN1 | – | 10 | 22 | | | |
| | SM5009CN2S, CF5009CN2 | – | 7 | 15 | | | |
| \overline{INH} pull-up resistance | R_{UP} | Measurement cct 4, $V_{DD} = 5V$, $\overline{INH} = V_{SS}$ | 40 | – | 200 | $k\Omega$ | |
| Negative resistance | $-R_L$ | $V_{DD} = 5V$, $T_a = 25^\circ C$, 40MHz | – | –210 | – | Ω | |
| Feedback resistance | R_f | Measurement cct 5 | 0.4 | – | 1.1 | $M\Omega$ | |
| Built-in capacitance | C_G | Design value. A monitor pattern on a wafer is tested. | 5.58 | 6 | 6.42 | pF | |
| | C_D | | 9.3 | 10 | 10.7 | pF | |

SM5009 series

5009AK× series

$V_{DD} = 4.5$ to $5.5V$, $V_{SS} = 0V$, $T_a = -40$ to $85^{\circ}C$ unless otherwise noted.

| Parameter | Symbol | Condition | Rating | | | Unit | |
|-------------------------------------|----------|--|------------|------|------|-----------|----|
| | | | min | typ | max | | |
| HIGH-level output voltage | V_{OH} | Q: Measurement cct 1, $I_{OH} = 16mA$ | 4.0 | – | – | V | |
| LOW-level output voltage | V_{OL} | Q: Measurement cct 1, $I_{OL} = 16mA$ | – | – | 0.4 | V | |
| HIGH-level input voltage | V_{IH} | \overline{INH} | 2.0 | – | – | V | |
| LOW-level input voltage | V_{IL} | \overline{INH} | – | – | 0.8 | V | |
| Output leakage current | I_Z | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OH} = V_{DD}$ | – | – | 10 | μA | |
| | | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OL} = V_{SS}$ | – | – | 10 | | |
| Current consumption | I_{DD} | $\overline{INH} = open$, Measurement cct 3, load cct 1, $C_L = 15pF$, 40MHz crystal oscillator, $T_a = -20$ to $+80^{\circ}C$ | SM5009AK1S | – | 12 | 26 | mA |
| | | | CF5009AK1 | – | 12 | 26 | |
| | | | SM5009AK2S | – | 8 | 17 | |
| | | | CF5009AK2 | – | 8 | 17 | |
| \overline{INH} pull-up resistance | R_{UP} | Measurement cct 4, $V_{DD} = 5V$, $\overline{INH} = V_{SS}$ | 40 | – | 200 | $k\Omega$ | |
| Negative resistance | $-R_L$ | $V_{DD} = 5V$, $T_a = 25^{\circ}C$, 40MHz | – | –210 | – | Ω | |
| Feedback resistance | R_f | Measurement cct 5 | 0.4 | – | 1.1 | $M\Omega$ | |
| Built-in capacitance | C_G | Design value. A monitor pattern on a wafer is tested. | 5.58 | 6 | 6.42 | pF | |
| | C_D | | 9.3 | 10 | 10.7 | pF | |

SM5009 series

5009AH× series

3V operation: $V_{DD} = 2.7$ to $3.3V$, $V_{SS} = 0V$, $T_a = -20$ to $80^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | Rating | | | Unit | |
|-------------------------------------|----------|--|--|------|------|-----------|----|
| | | | min | typ | max | | |
| HIGH-level output voltage | V_{OH} | Q: Measurement cct 1, $I_{OH} = 2mA$ | 2.2 | – | – | V | |
| LOW-level output voltage | V_{OL} | Q: Measurement cct 1, $I_{OL} = 2mA$ | – | – | 0.4 | V | |
| HIGH-level input voltage | V_{IH} | \overline{INH} | 2.0 | – | – | V | |
| LOW-level input voltage | V_{IL} | \overline{INH} | – | – | 0.3 | V | |
| Output leakage current | I_z | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OH} = V_{DD}$ | – | – | 10 | μA | |
| | | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OL} = V_{SS}$ | – | – | 10 | | |
| Current consumption | I_{DD} | $\overline{INH} = open$, Measurement cct 3, load cct 2, $C_L = 15pF$, 16MHz crystal oscillator | SM5009AH1S CF5009AH1 | – | 4.5 | 10 | mA |
| | | | SM5009AH2S CF5009AH2 | – | 3 | 7 | |
| | | | SM5009AH3S CF5009AH3 SM5009AH4S CF5009AH4 | – | 1.5 | 3.5 | |
| \overline{INH} pull-up resistance | R_{UP} | Measurement cct 4, $V_{DD} = 3V$, $\overline{INH} = V_{SS}$ | 40 | – | 200 | $k\Omega$ | |
| Negative resistance | $-R_L$ | $V_{DD} = 3V$, $T_a = 25^\circ C$, 16MHz | – | –450 | – | Ω | |
| Feedback resistance | R_f | Measurement cct 5 | 0.4 | – | 1.1 | $M\Omega$ | |
| Built-in capacitance | C_G | Design value. A monitor pattern on a wafer is tested. | 5.58 | 6 | 6.42 | pF | |
| | C_D | | 9.3 | 10 | 10.7 | pF | |

5V operation: $V_{DD} = 4.5$ to $5.5V$, $V_{SS} = 0V$, $T_a = -40$ to $85^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | Rating | | | Unit | |
|-------------------------------------|----------|--|--|------|------|-----------|----|
| | | | min | typ | max | | |
| HIGH-level output voltage | V_{OH} | Q: Measurement cct 1, $I_{OH} = 4mA$ | 4.0 | – | – | V | |
| LOW-level output voltage | V_{OL} | Q: Measurement cct 1, $I_{OL} = 4mA$ | – | – | 0.4 | V | |
| HIGH-level input voltage | V_{IH} | \overline{INH} | 2.0 | – | – | V | |
| LOW-level input voltage | V_{IL} | \overline{INH} | – | – | 0.8 | V | |
| Output leakage current | I_z | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OH} = V_{DD}$ | – | – | 10 | μA | |
| | | Q: Measurement cct 2, $\overline{INH} = LOW$, $V_{OL} = V_{SS}$ | – | – | 10 | | |
| Current consumption | I_{DD} | $\overline{INH} = open$, Measurement cct 3, load cct 2, $C_L = 15pF$, 30MHz crystal oscillator | SM5009AH1S CF5009AH1 | – | 9 | 20 | mA |
| | | | SM5009AH2S CF5009AH2 | – | 6 | 13 | |
| | | | SM5009AH3S CF5009AH3 SM5009AH4S CF5009AH4 | – | 4 | 9 | |
| \overline{INH} pull-up resistance | R_{UP} | Measurement cct 4, $V_{DD} = 5V$, $\overline{INH} = V_{SS}$ | 40 | – | 200 | $k\Omega$ | |
| Negative resistance | $-R_L$ | $V_{DD} = 5V$, $T_a = 25^\circ C$, 30MHz | – | –340 | – | Ω | |
| Feedback resistance | R_f | Measurement cct 5 | 0.4 | – | 1.1 | $M\Omega$ | |
| Built-in capacitance | C_G | Design value. A monitor pattern on a wafer is tested. | 5.58 | 6 | 6.42 | pF | |
| | C_D | | 9.3 | 10 | 10.7 | pF | |

Switching Characteristics

5009AL× series

3V operation: $V_{DD} = 2.7$ to $3.3V$, $V_{SS} = 0V$, $T_a = -40$ to $85^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | Rating | | | Unit | |
|--|-----------|--|---------------------------------------|------|-----|------|-----|
| | | | min | typ | max | | |
| Output rise time | t_{r1} | Measurement cct 3, load cct 2, $0.1V_{DD}$ to $0.9V_{DD}$, $C_L = 15pF$ | – | 3.5 | 9 | ns | |
| | | Measurement cct 3, load cct 2, $0.1V_{DD}$ to $0.9V_{DD}$, $V_{DD} = 2.3$ to $2.7V$, $T_a = -20$ to $+80^\circ C$, $C_L = 15pF$ | – | 4 | 13 | | |
| | t_{r2} | Measurement cct 3, load cct 2, $0.1V_{DD}$ to $0.9V_{DD}$, $C_L = 30pF$ | – | 5 | 12 | | |
| | | Measurement cct 3, load cct 2, $0.1V_{DD}$ to $0.9V_{DD}$, $V_{DD} = 2.4$ to $2.7V$, $T_a = -20$ to $+80^\circ C$, $C_L = 30pF$ | – | 5.5 | 16 | | |
| | t_{r3} | Measurement cct 3, load cct 2, $0.1V_{DD}$ to $0.9V_{DD}$, $V_{DD} = 3.0$ to $3.6V$, $f \leq 30MHz$, $C_L = 50pF$ | – | 5 | 12 | | |
| | | Measurement cct 3, load cct 2, $0.2V_{DD}$ to $0.8V_{DD}$, $V_{DD} = 3.0$ to $3.6V$, $f \leq 40MHz$, $C_L = 50pF$ | – | 3.5 | 12 | | |
| Output fall time | t_{f1} | Measurement cct 3, load cct 2, $0.9V_{DD}$ to $0.1V_{DD}$, $C_L = 15pF$ | – | 3.5 | 9 | ns | |
| | | Measurement cct 3, load cct 2, $0.9V_{DD}$ to $0.1V_{DD}$, $V_{DD} = 2.3$ to $2.7V$, $T_a = -20$ to $+80^\circ C$, $C_L = 15pF$ | – | 4 | 13 | | |
| | t_{f2} | Measurement cct 3, load cct 2, $0.9V_{DD}$ to $0.1V_{DD}$, $C_L = 30pF$ | – | 5 | 12 | | |
| | | Measurement cct 3, load cct 2, $0.9V_{DD}$ to $0.1V_{DD}$, $V_{DD} = 2.4$ to $2.7V$, $T_a = -20$ to $+80^\circ C$, $C_L = 30pF$ | – | 5.5 | 16 | | |
| | t_{f3} | Measurement cct 3, load cct 2, $0.9V_{DD}$ to $0.1V_{DD}$, $V_{DD} = 3.0$ to $3.6V$, $f \leq 30MHz$, $C_L = 50pF$ | – | 5 | 12 | | |
| | | Measurement cct 3, load cct 2, $0.8V_{DD}$ to $0.2V_{DD}$, $V_{DD} = 3.0$ to $3.6V$, $f \leq 40MHz$, $C_L = 50pF$ | – | 3.5 | 12 | | |
| Output duty cycle ¹ | Duty1 | Measurement cct 3, load cct 2, $V_{DD} = 3V$, $f \leq 40MHz$, $T_a = 25^\circ C$, $C_L = 30pF$ | 45 | – | 55 | % | |
| | | Measurement cct 3, load cct 2, $V_{DD} = 2.4V$, $f \leq 14.4MHz$, $T_a = 25^\circ C$, $C_L = 30pF$ | 40 | – | 60 | | |
| | | CF5009AL× only, Measurement cct 3, load cct 2, $V_{DD} = 2.5V$, $f \leq 30MHz$, $T_a = 25^\circ C$, $C_L = 15pF$ | 40 | – | 60 | | |
| | Duty2 | CF5009AL× only, Measurement cct 3, load cct 2, $V_{DD} = 3.3V$, $f \leq 30MHz$, $T_a = 25^\circ C$, $C_L = 50pF$ | 45 | – | 55 | | |
| | | CF5009AL× only, Measurement cct 3, load cct 2, $V_{DD} = 3.3V$, $f \leq 40MHz$, $T_a = 25^\circ C$, $C_L = 50pF$ | 40 | – | 60 | | |
| Output disable delay time ² | t_{PLZ} | Measurement cct 6, load cct 2, $V_{DD} = 3V$, $T_a = 25^\circ C$, $C_L \leq 15pF$ | – | – | 100 | ns | |
| Output enable delay time ² | t_{PZL} | | – | – | 100 | ns | |
| Maximum operating frequency | f_{max} | Measurement cct 3 | CF5009AL× | 40 | – | – | MHz |
| | | | SM5009AL×S | 30 | – | – | |
| | | Measurement cct 3, $T_a = -20$ to $+80^\circ C$ | SM5009AL×S | 40 | – | – | |
| | | Measurement cct 3, $T_a = -20$ to $+80^\circ C$ | $V_{DD} = 2.4$ to $2.7V$, SM5009AL×S | 14.4 | – | – | |
| | | | $V_{DD} = 2.3$ to $2.7V$, CF5009AL× | 30 | – | – | |
| $V_{DD} = 2.25$ to $2.75V$, CF5009AL× | 20 | – | – | | | | |

1. The duty cycle characteristic is checked the sample chips of each production lot.

2. Oscillator stop function is built-in. When \overline{INH} goes LOW, normal output stops. When \overline{INH} goes HIGH, normal output is not resumed until after the oscillator start-up time has elapsed.

SM5009 series

5V operation: $V_{DD} = 4.5$ to $5.5V$, $V_{SS} = 0V$, $T_a = -40$ to $85^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | | Rating | | | Unit |
|--|-----------|---|--------------|--------|-----|-----|------|
| | | | | min | typ | max | |
| Output rise time | t_{r1} | Measurement cct 3, load cct 2, $0.1V_{DD}$ to $0.9V_{DD}$ | $C_L = 15pF$ | – | 2 | 4 | ns |
| | t_{r2} | | $C_L = 30pF$ | – | 3.5 | 7 | |
| | t_{r3} | | $C_L = 50pF$ | – | 4 | 8 | |
| Output fall time | t_{f1} | Measurement cct 3, load cct 2, $0.9V_{DD}$ to $0.1V_{DD}$ | $C_L = 15pF$ | – | 2 | 4 | ns |
| | t_{f2} | | $C_L = 30pF$ | – | 3.5 | 7 | |
| | t_{f3} | | $C_L = 50pF$ | – | 4 | 8 | |
| Output duty cycle ¹ | Duty | Measurement cct 3, load cct 2, $V_{DD} = 5V$, $T_a = 25^\circ C$, $C_L = 50pF$ | | 45 | – | 55 | % |
| Output disable delay time ² | t_{PLZ} | Measurement cct 6, load cct 2, $V_{DD} = 5V$, $T_a = 25^\circ C$, $C_L \leq 15pF$ | | – | – | 100 | ns |
| Output enable delay time ² | t_{PZL} | | | – | – | 100 | ns |
| Maximum operating frequency | f_{max} | Measurement cct 3 | CF5009AL× | 40 | – | – | MHz |
| | | | SM5009AL×S | 30 | – | – | |
| | | Measurement cct 3, $T_a = -20$ to $+80^\circ C$ | SM5009AL×S | 40 | – | – | |

1. The duty cycle characteristic is checked the sample chips of each production lot.

2. Oscillator stop function is built-in. When \overline{INH} goes LOW, normal output stops. When \overline{INH} goes HIGH, normal output is not resumed until after the oscillator start-up time has elapsed.

SM5009 series

5009AN×/CN× series

3V operation: $V_{DD} = 2.7$ to $3.3V$, $V_{SS} = 0V$, $T_a = -20$ to $80^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | | Rating | | | Unit |
|--------------------------------|-----------|---|--|--------|-----|-----|------|
| | | | | min | typ | max | |
| Output rise time | t_{r1} | Measurement cct 3, load cct 2, $0.1V_{DD}$ to $0.9V_{DD}$, $C_L = 15pF$ | SM5009AN1S, CF5009AN1 SM5009AN2S, CF5009AN2 | – | 3.5 | 9 | ns |
| | | | SM5009AN3S, CF5009AN3 SM5009AN4S, CF5009AN4 SM5009AN5S, CF5009AN5 SM5009AN6S, CF5009AN6 SM5009CN1S, CF5009CN1 SM5009CN2S, CF5009CN2 | – | 5 | 13 | |
| | t_{r2} | Measurement cct 3, load cct 2, $0.1V_{DD}$ to $0.9V_{DD}$, $C_L = 30pF$ | SM5009AN1S, CF5009AN1 SM5009AN2S, CF5009AN2 | – | 5 | 12 | |
| | | | SM5009AN3S, CF5009AN3 SM5009AN4S, CF5009AN4 SM5009AN5S, CF5009AN5 SM5009AN6S, CF5009AN6 SM5009CN1S, CF5009CN1 SM5009CN2S, CF5009CN2 | – | 7 | 16 | |
| Output fall time | t_{f1} | Measurement cct 3, load cct 2, $0.9V_{DD}$ to $0.1V_{DD}$, $C_L = 15pF$ | SM5009AN1S, CF5009AN1 SM5009AN2S, CF5009AN2 | – | 3.5 | 9 | ns |
| | | | SM5009AN3S, CF5009AN3 SM5009AN4S, CF5009AN4 SM5009AN5S, CF5009AN5 SM5009AN6S, CF5009AN6 SM5009CN1S, CF5009CN1 SM5009CN2S, CF5009CN2 | – | 5 | 13 | |
| | t_{f2} | Measurement cct 3, load cct 2, $0.9V_{DD}$ to $0.1V_{DD}$, $C_L = 30pF$ | SM5009AN1S, CF5009AN1 SM5009AN2S, CF5009AN2 | – | 5 | 12 | |
| | | | SM5009AN3S, CF5009AN3 SM5009AN4S, CF5009AN4 SM5009AN5S, CF5009AN5 SM5009AN6S, CF5009AN6 SM5009CN1S, CF5009CN1 SM5009CN2S, CF5009CN2 | – | 7 | 16 | |
| Output duty cycle ¹ | Duty | Measurement cct 3, load cct 2, $V_{DD} = 3V$, $T_a = 25^\circ C$ | $C_L = 30 pF$, SM5009AN×S, CF5009AN× | 45 | – | 55 | % |
| | | | $C_L = 15 pF$, SM5009CN×S, CF5009CN× | 40 | – | 60 | |
| Output disable delay time | t_{PLZ} | Measurement cct 6, load cct 2, $V_{DD} = 3V$, $T_a = 25^\circ C$, $C_L \leq 15pF$ | | – | – | 100 | ns |
| Output enable delay time | t_{PZL} | | | – | – | 100 | ns |
| Maximum operating frequency | f_{max} | Measurement cct 3 | SM5009AN×S, CF5009AN× | 40 | – | – | MHz |
| | | | $T_a = -10$ to $+70^\circ C$, SM5009CN×S, CF5009CN× | 30 | – | – | |

1. The duty cycle characteristic is checked the sample chips of each production lot.

SM5009 series

5V operation: $V_{DD} = 4.5$ to $5.5V$, $V_{SS} = 0V$, $T_a = -40$ to $85^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | | Rating | | | Unit |
|--------------------------------|-----------|---|-----------------------|--------|-----|-----|------|
| | | | | min | typ | max | |
| Output rise time | t_{r1} | Measurement cct 3, load cct 2, $0.1V_{DD}$ to $0.9V_{DD}$ | $C_L = 15pF$ | – | 2 | 4 | ns |
| | t_{r2} | | $C_L = 30pF$ | – | 3.5 | 7 | |
| | t_{r3} | | $C_L = 50pF$ | – | 4 | 8 | |
| Output fall time | t_{f1} | Measurement cct 3, load cct 2, $0.9V_{DD}$ to $0.1V_{DD}$ | $C_L = 15pF$ | – | 2 | 4 | ns |
| | t_{f2} | | $C_L = 30pF$ | – | 3.5 | 7 | |
| | t_{f3} | | $C_L = 50pF$ | – | 4 | 8 | |
| Output duty cycle ¹ | Duty | Measurement cct 3, load cct 2, $V_{DD} = 5V$, $T_a = 25^\circ C$, $C_L = 50pF$ | | 45 | – | 55 | % |
| Output disable delay time | t_{PLZ} | Measurement cct 6, load cct 2, $V_{DD} = 5V$, $T_a = 25^\circ C$, $C_L \leq 15pF$ | | – | – | 100 | ns |
| Output enable delay time | t_{PZL} | | | – | – | 100 | ns |
| Maximum operating frequency | f_{max} | Measurement cct 3 | SM5009AN×S, CF5009AN× | 40 | – | – | MHz |
| | | | SM5009CN×S, CF5009CN× | 30 | – | – | |

1. The duty cycle characteristic is checked the sample chips of each production lot.

5009AK× series

$V_{DD} = 4.5$ to $5.5V$, $V_{SS} = 0V$, $T_a = -40$ to $85^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | | Rating | | | Unit |
|--------------------------------|-----------|---|------------------------------|--------|-----|-----|------|
| | | | | min | typ | max | |
| Output rise time | t_r | Measurement cct 3, load cct 1, $0.4V$ to $2.4V$, $C_L = 15pF$ | | – | 2 | 6 | ns |
| Output fall time | t_f | Measurement cct 3, load cct 1, $2.4V$ to $0.4V$, $C_L = 15pF$ | | – | 2 | 6 | ns |
| Output duty cycle ¹ | Duty | Measurement cct 3, load cct 1, $V_{DD} = 5V$, $T_a = 25^\circ C$, $C_L = 15pF$ | | 45 | – | 55 | % |
| Output disable delay time | t_{PLZ} | Measurement cct 6, load cct 1, $V_{DD} = 5V$, $T_a = 25^\circ C$, $C_L \leq 15pF$ | | – | – | 100 | ns |
| Output enable delay time | t_{PZL} | | | – | – | 100 | ns |
| Maximum operating frequency | f_{max} | Measurement cct 3 | $T_a = -20$ to $+80^\circ C$ | 40 | – | – | MHz |
| | | | $T_a = -40$ to $+85^\circ C$ | 30 | – | – | |

1. The duty cycle characteristic is checked the sample chips of each production lot.

SM5009 series

5009AH× series

3V operation: $V_{DD} = 2.7$ to $3.3V$, $V_{SS} = 0V$, $T_a = -20$ to $80^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | Rating | | | Unit |
|--------------------------------|-----------|---|--------|-----|-----|------|
| | | | min | typ | max | |
| Output rise time | t_{r1} | Measurement cct 3, load cct 2, $0.1V_{DD}$ to $0.9V_{DD}$, $C_L = 15pF$ | – | 6 | 18 | ns |
| Output fall time | t_{f1} | Measurement cct 3, load cct 2, $0.9V_{DD}$ to $0.1V_{DD}$, $C_L = 15pF$ | – | 6 | 18 | ns |
| Output duty cycle ¹ | Duty | Measurement cct 3, load cct 2, $V_{DD} = 3V$, $T_a = 25^\circ C$, $C_L = 15pF$ | 45 | – | 55 | % |
| Output disable delay time | t_{PLZ} | Measurement cct 6, load cct 2, $V_{DD} = 3V$, $T_a = 25^\circ C$, $C_L \leq 15pF$ | – | – | 100 | ns |
| Output enable delay time | t_{PZL} | | – | – | 100 | ns |
| Maximum operating frequency | f_{max} | Measurement cct 3 | 16 | – | – | MHz |

1. The duty cycle characteristic is checked the sample chips of each production lot.

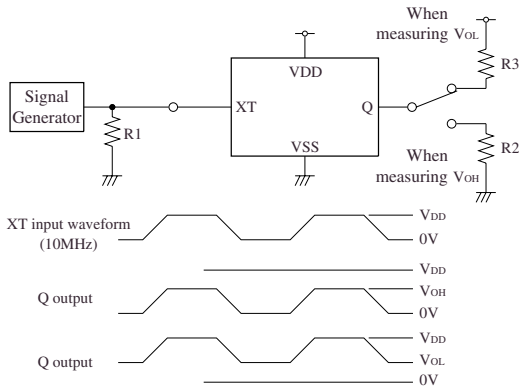
5V operation: $V_{DD} = 4.5$ to $5.5V$, $V_{SS} = 0V$, $T_a = -40$ to $85^\circ C$ unless otherwise noted.

| Parameter | Symbol | Condition | Rating | | | Unit |
|--------------------------------|-----------|---|--------|-----|-----|------|
| | | | min | typ | max | |
| Output rise time | t_{r1} | Measurement cct 3, load cct 2, $0.1V_{DD}$ to $0.9V_{DD}$, $C_L = 15pF$ | – | 4 | 12 | ns |
| Output fall time | t_{f1} | Measurement cct 3, load cct 2, $0.9V_{DD}$ to $0.1V_{DD}$, $C_L = 15pF$ | – | 4 | 12 | ns |
| Output duty cycle ¹ | Duty | Measurement cct 3, load cct 2, $V_{DD} = 5V$, $T_a = 25^\circ C$, $C_L = 15pF$ | 45 | – | 55 | % |
| Output disable delay time | t_{PLZ} | Measurement cct 6, load cct 2, $V_{DD} = 5V$, $T_a = 25^\circ C$, $C_L \leq 15pF$ | – | – | 100 | ns |
| Output enable delay time | t_{PZL} | | – | – | 100 | ns |
| Maximum operating frequency | f_{max} | Measurement cct 3 | 30 | – | – | MHz |

1. The duty cycle characteristic is checked the sample chips of each production lot.

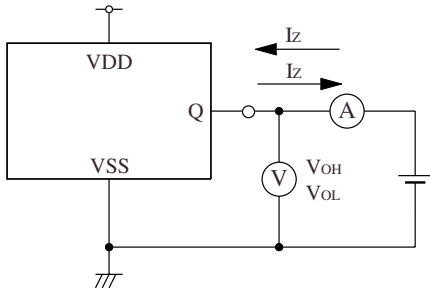
MEASUREMENT CIRCUITS

Measurement cct 1

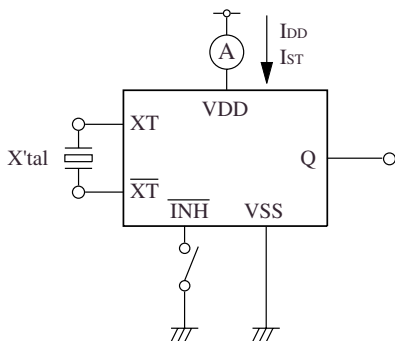


- 5009AKx, ALx, AN1, AN2
 R1: 50Ω
 R2: 250Ω(V_{DD} = 4.5V), 275Ω(V_{DD} = 2.7V)
 R3: 256Ω(V_{DD} = 4.5V), 288Ω(V_{DD} = 2.7V)
- 5009AN3 to AN6, CNx
 R1: 50Ω
 R2: 245Ω(V_{DD} = 4.5V), 262Ω(V_{DD} = 2.7V)
 R3: 256Ω(V_{DD} = 4.5V), 288Ω(V_{DD} = 2.7V)
- 5009AHx
 R1: 50Ω
 R2: 1000Ω(V_{DD} = 4.5V), 1100Ω(V_{DD} = 2.7V)
 R3: 1025Ω(V_{DD} = 4.5V), 1150Ω(V_{DD} = 2.7V)

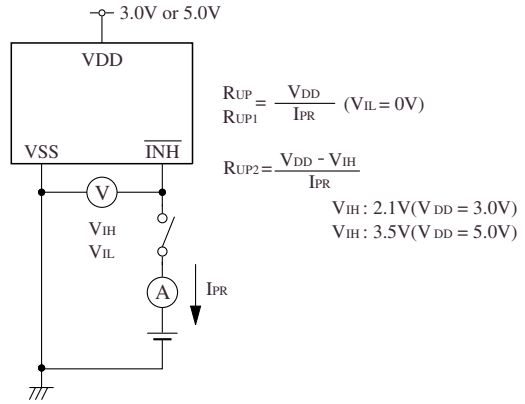
Measurement cct 2



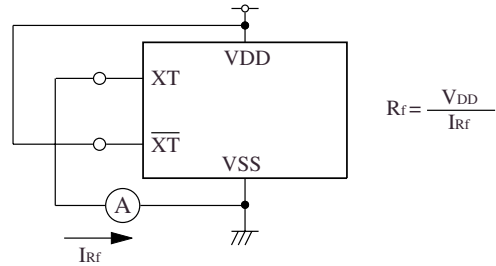
Measurement cct 3



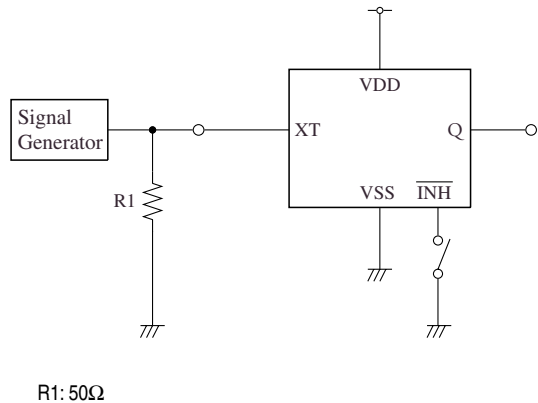
Measurement cct 4



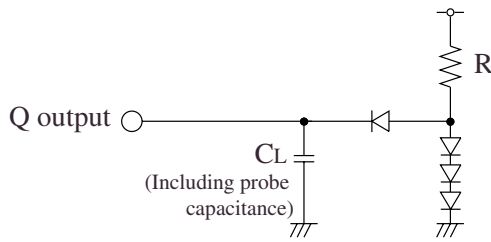
Measurement cct 5



Measurement cct 6

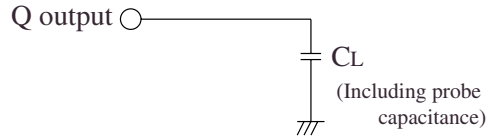


Load cct 1



$C_L = 15\text{pF}$: DUTY, I_{DD} , t_p , t_f
 $R = 400\Omega$

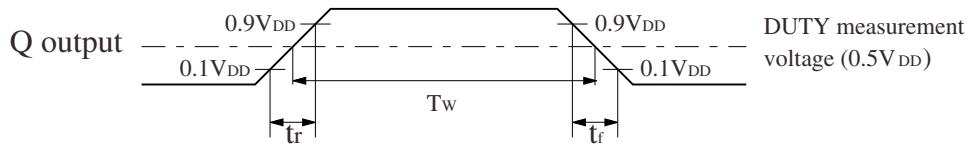
Load cct 2



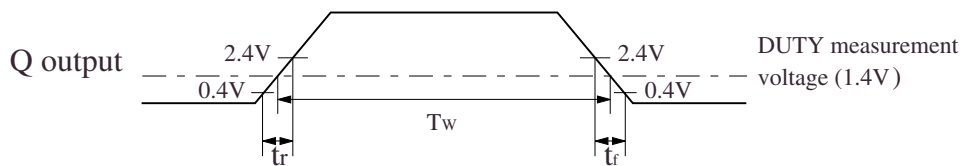
$C_L = 15\text{pF}$: DUTY, I_{DD} , t_{r1} , t_{f1}
 $C_L = 30\text{pF}$: t_{r2} , t_{f2}
 $C_L = 50\text{pF}$: t_{r3} , t_{f3}

Switching Time Measurement Waveform

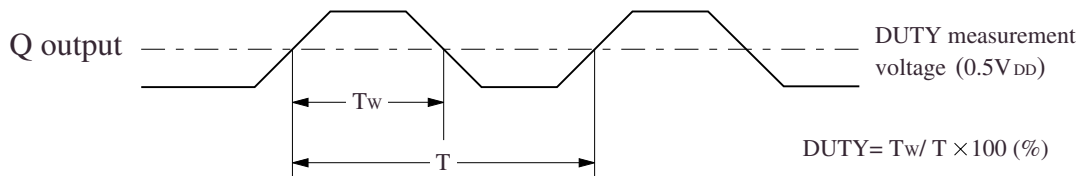
Output duty level (CMOS)



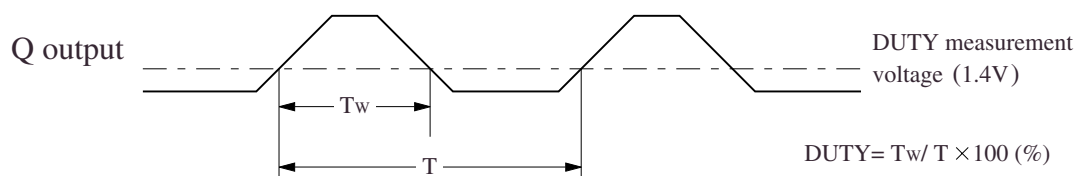
Output duty level (TTL)



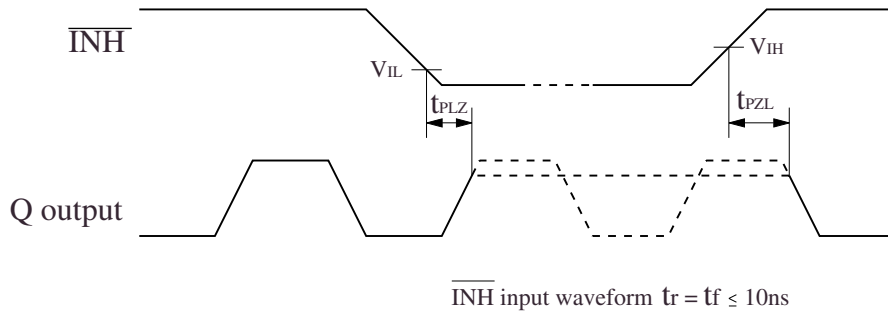
Output duty cycle (CMOS)



Output duty cycle (TTL)



Output Enable/Disable Delay



Note (AL× series only): when the device is in standby, the oscillator stops. When standby is released, the oscillator starts and stable oscillator output occurs after a short delay.

Please pay your attention to the following points at time of using the products shown in this document.

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